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Nanotehnologije - Slovar - 13. del: Grafen in sorodni dvodimenzionalni (2D) materiali (ISO/TS 80004-13:2017)

Nanotechnologies - Vocabulary - Part 13: Graphene and related two-dimensional (2D) materials (ISO/TS 80004-13:2017)

Nanotechnologien - Fachwörterverzeichnis - Teil 13: Graphen und andere zweidimensionale (2D) Werkstoffe (ISO/TS 80004-13:2017)

Nanotechnologies - Vocabulaire Partie 13: Graphene et autres matériaux bidimensionnels (ISO/TS 80004-13:2017)

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Nanotechnologien - Fachwörterverzeichnis - Teil 13: Graphen und andere zweidimensionale (2D) Werkstoffe (ISO/TS 80004-13:2017)

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CEN ISO/TS 80004-13:2020 (E)

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CEN ISO/TS 80004-13:2020 (E)

European foreword

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Part 13:

Graphene and related twodimensional (2D) materials

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Foreword

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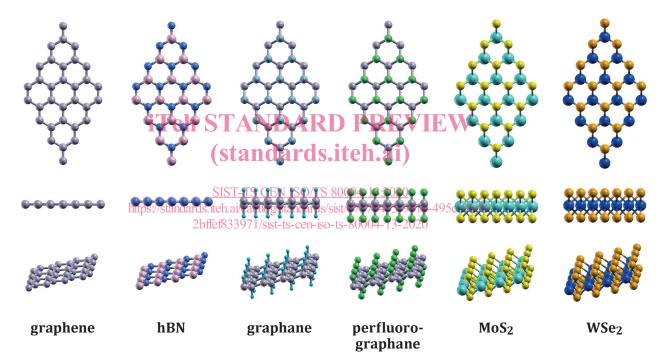
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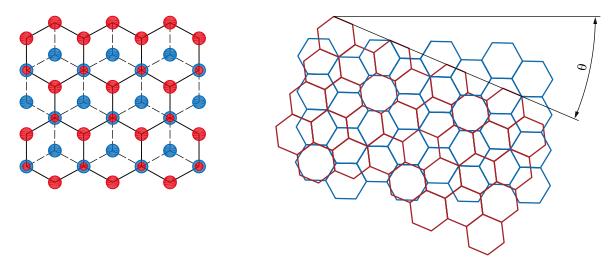
A list of all parts in the ISO 80004 series can be found on the ISO website.

Introduction

Over the last decade, huge interest has arisen in graphene both scientifically and commercially, due to the many exceptional properties associated with this material, properties such as the electrical and thermal conductivity. More recently, other materials with a structure similar to that of graphene have also shown promising properties including monolayer and few-layer versions of hexagonal boron nitride (hBN), molybdenum disulphide (MoS₂), tungsten diselenide (WSe₂), silicene and germanene and layered assemblies of mixtures of these materials. These materials have their thickness constrained within the nanoscale or smaller and consist of between one and several layers. These materials are thus termed two-dimensional (2D) materials as they have one dimension at the nanoscale or smaller, with the other two dimensions generally at scales larger than the nanoscale. A layered material consists of two-dimensional layers weakly stacked or bound to form three-dimensional structures. Examples of 2D materials and the different stacking configurations in graphene are shown in Figure 1. It should be noted that 2D materials are not necessarily topographically flat in reality and can have a buckled structure. They can also form aggregates and agglomerates which can have different morphologies. Two-dimensional materials are an important subset of nanomaterials.



a) Examples of different two-dimensional materials consisting of different elements and structures, as shown by the different coloured orbs and top-down and side views



b) Bernal stacked bilayer graphene (3.1.2.6)

c) turbostratic bilayer or twisted bilayer graphene with relative stacking angle, θ , (3.1.2.7)



ABC trilayer

d) Bernal stacked (AB) (3.4.1.10) tri-layer graphene (3.1.2.9) and Rhombohedral (ABC) (3.4.1.11) stacked tri-layer graphene (3.1.2.9)

Figure 1 — Examples of 2D materials and the different stacking configurations in graphene layers

It is important to standardize the terminology for graphene, graphene-derived and related 2D materials at the international level, as the number of publications, patents and organizations is increasing rapidly. Thus, these materials need an associated vocabulary as they become commercialized and sold throughout the world.

This document belongs to a multi-part vocabulary covering the different aspects of nanotechnologies. It builds upon ISO/TS 80004-3, ISO/TS 80004-11 and ISO/TS 80004-6 and uses existing definitions where possible.